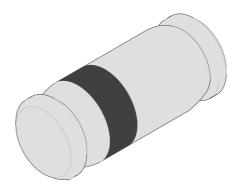


Silicon Planar Diodes

Features

- Low differential forward resistance
- Low diode capacitance
- High reverse impedance



94 9371

Applications

Band switching in VHF-tuners

Absolute Maximum Ratings

$T_j = 25^{\circ}C$					
Parameter	Test Conditions	Туре	Symbol	Value	Unit
Reverse voltage			V _R	35	V
Forward current			I _F	100	mA
Junction temperature			Т _і	150	°C
Storage temperature range			T _{stg}	-55+150	°C

Maximum Thermal Resistance

T_i = 25°C

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	on PC board 50mmx50mmx1.6mm	R _{thJA}	500	K/W

Electrical Characteristics

 $T_j = 25^{\circ}C$

Parameter	Test Conditions	Туре	Symbol	Min	Тур	Max	Unit
Forward voltage	I _F =100mA		V _F			1	V
Reverse current	V _R =20V		I _R			50	nA
Diode capacitance	f=100MHz, V _R =1V		CD			1.5	pF
	f=100MHz, V _R =3V	BA682	CD			1.25	pF
	f=100MHz, V _R =3V	BA683	CD			1.2	pF
Differential forward	f=200MHz, I _F =3mA	BA682	r _f			0.7	Ω
resistance	f=200MHz, I _F =3mA	BA683	r _f			1.2	Ω
	f=200MHz, I _F =10mA	BA682	r _f			0.5	Ω
	f=200MHz, I _F =10mA	BA683	r _f			0.9	Ω

BA682.BA683



Vishay Telefunken

Characteristics ($T_j = 25^{\circ}C$ unless otherwise specified)

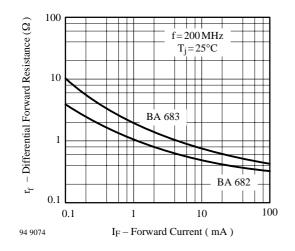


Figure 1. Differential Forward Resistance vs. Forward Current

Cathode indification

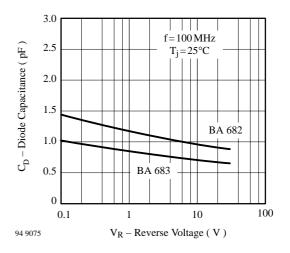
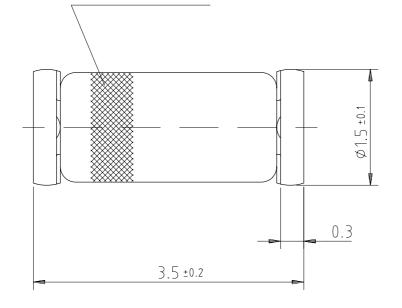
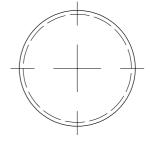


Figure 2. Diode Capacitance vs. Reverse Voltage







technical drawings according to DIN specifications

96 12070

Dimensions in mm

Glass case

Mini MELF / SOD 80

JEDEC DO 213 AA



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems

with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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